

# BRCS350P04YM

Rev.A Oct.-2024

## 描述 / Descriptions

PDFN5×6A 塑封封装双 P 沟道场效应管。  
Dual P-CHANNEL MOSFET in a PDFN5×6A Plastic Package.

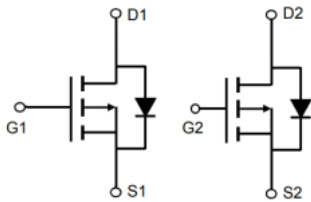
## 特征 / Features

$V_{DS}(V)=-40V$        $I_D=-20A$   
 $R_{DS(ON)}@-10V<35\text{ m}\Omega$ (Typ. 33 m $\Omega$ )  
 $R_{DS(ON)}@-4.5V<60\text{ m}\Omega$ (Typ. 40 m $\Omega$ )  
 无卤产品。HF Product.

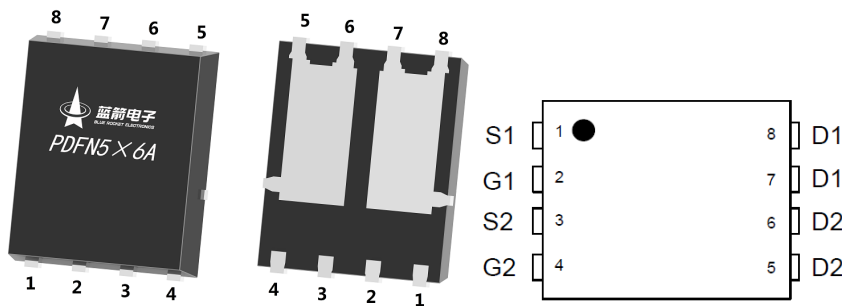
## 用途 / Applications

笔记本电脑、便携式设备和电池供电系统的电源管理。  
Power Management in Notebook Computer, Portable Equipment and Battery Powered Systems.

## 内部等效电路 / Equivalent Circuit



## 引脚排列 / Pinning



## 印章代码 / Marking

见印章说明。  
See Marking Instructions.

**极限参数 / Absolute Maximum Ratings(Ta=25°C)**

参数 Parameter	符号 Symbol	数值 Rating	单位 Unit
Drain-Source Voltage	V <sub>DSS</sub>	-40	V
Drain Current	I <sub>D</sub> (Tc=25°C)	-20	A
Drain Current - Pulsed	I <sub>DM</sub>	-46	A
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Avalanche Current	I <sub>AS</sub>	13	A
Single Pulsed Avalanche Energy (L=0.5mH)	E <sub>AS</sub>	54	mJ
Power Dissipation	P <sub>D</sub>	25	W
Storage Temperature Range	T <sub>stg</sub>	-55~150	°C
Thermal Resistance-Junction to Ambient	t ≤ 10s	40	°C/W
	Steady-State	62.5	
Thermal Resistance-Junction to Case	Steady-State	5	°C/W

**电性能参数 / Electrical Characteristics(Ta=25°C)**

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	-40	-46		V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-40V V <sub>GS</sub> =0V			1.0	μA
Gate-Body Leakage Current Forward	I <sub>GSS</sub>	V <sub>GS</sub> =±20V V <sub>DS</sub> =0V			±0.1	μA
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> I <sub>D</sub> =-250μA	-1.0	-1.4	-2.5	V
Static Drain-Source On-Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V I <sub>D</sub> =-20A		33	35	mΩ
		V <sub>GS</sub> =-4.5V I <sub>D</sub> =-10A		40	60	
Drain-Source Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V I <sub>S</sub> =-1A			-1.2	V
Gate resistance	R <sub>g</sub>	V <sub>GS</sub> =0V V <sub>DS</sub> =0V, f=1MHz		9.5		Ω
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =-25V V <sub>GS</sub> =0V f=1.0MHz		1500		pF
Output Capacitance	C <sub>oss</sub>			620		
Reverse Transfer Capacitance	C <sub>rss</sub>			440		
Total Gate Charge	Q <sub>g(-10V)</sub>	V <sub>GS</sub> =-10V V <sub>DS</sub> =-20V I <sub>D</sub> =-12A		16.5		nC
Total Gate Charge	Q <sub>g(-4.5V)</sub>			7.8		
Gate Source Charge	Q <sub>gs</sub>			4.2		
Gate Drain Charge	Q <sub>gd</sub>			3.8		

**电性能参数 / Electrical Characteristics(Ta=25°C)**

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=-10V$ $V_{DS}=-20V$ $R_L=1.6\Omega$ $R_{GEN}=3\Omega$		6.5		ns
Turn-On Rise Time	$t_r$			9.2		
Turn-Off Delay Time	$t_{d(off)}$			52		
Turn-Off Fall Time	$t_f$			50.8		

## 电参数曲线图 / Electrical Characteristic Curve

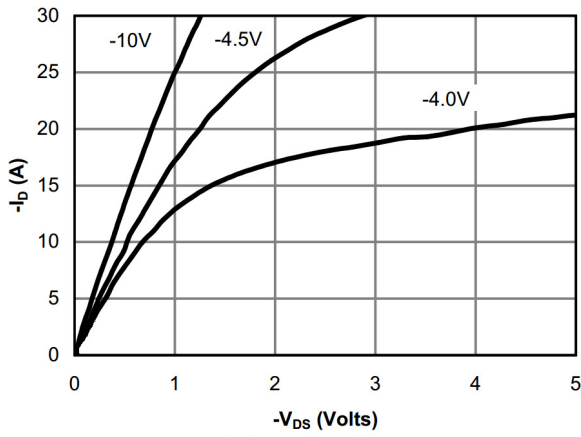


Figure 1: On-Region Characteristics

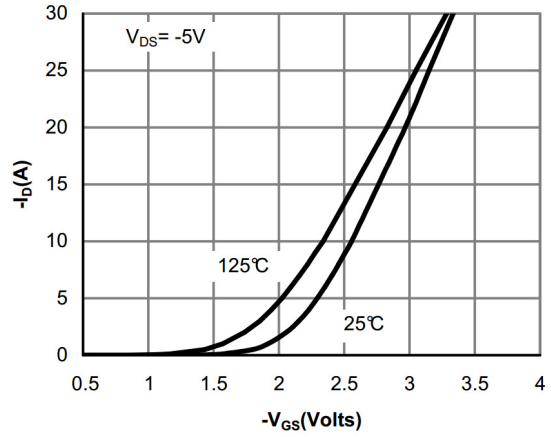


Figure 2: Transfer Characteristics

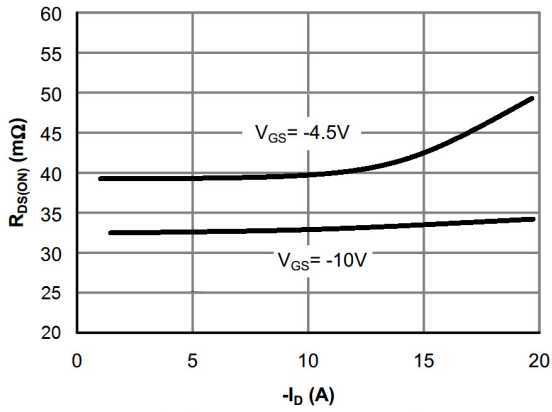


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

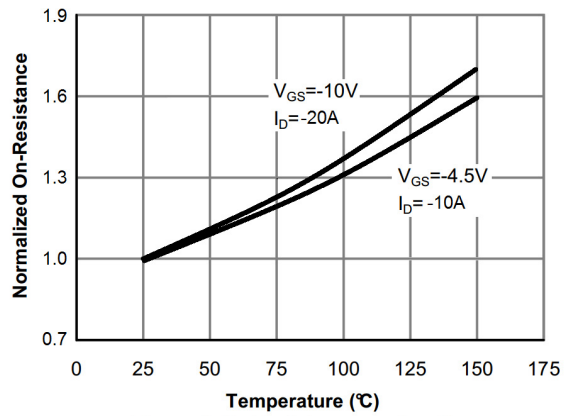


Figure 4: On-Resistance vs. Junction Temperature

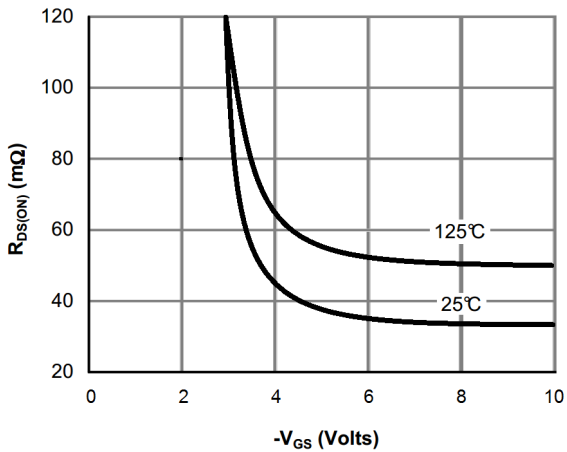


Figure 5: On-Resistance vs. Gate-Source Voltage

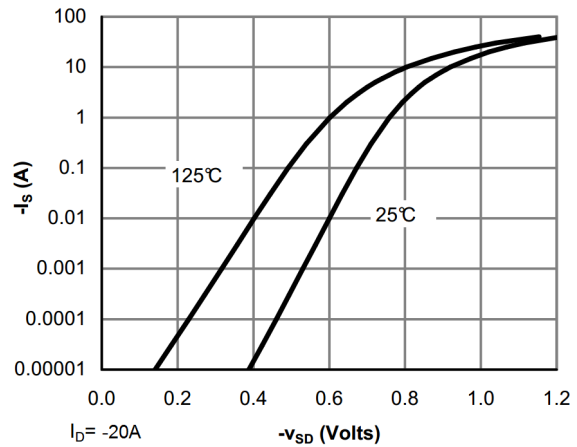


Figure 6: Body-Diode Characteristics

## 电参数曲线图 / Electrical Characteristic Curve

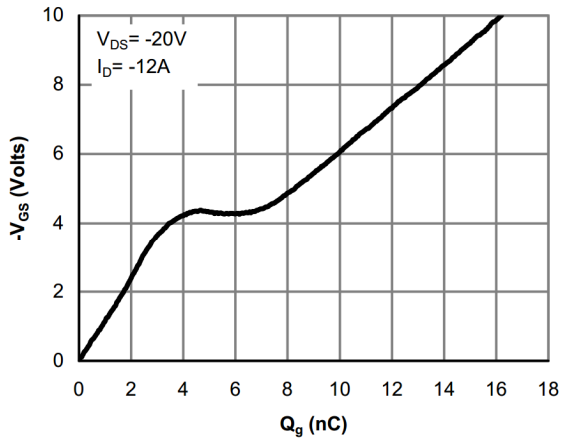


Figure 7: Gate-Charge Characteristics

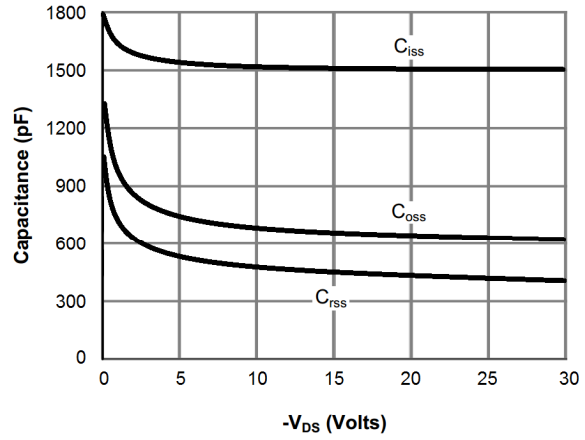


Figure 8: Capacitance Characteristics

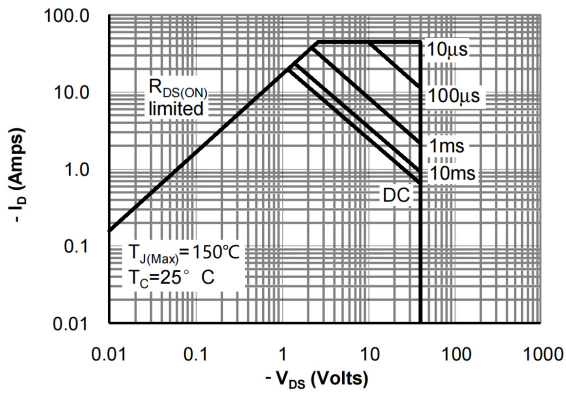


Figure 9: Maximum Forward Biased Safe Operating Area

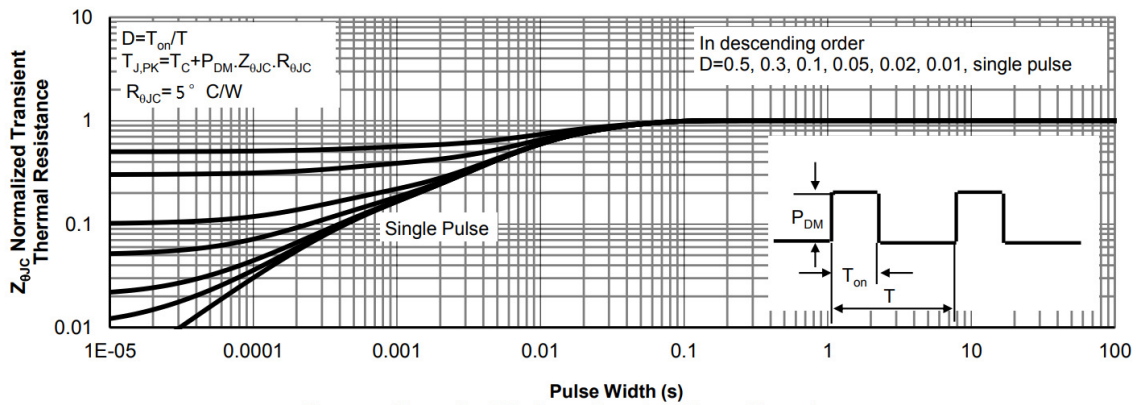
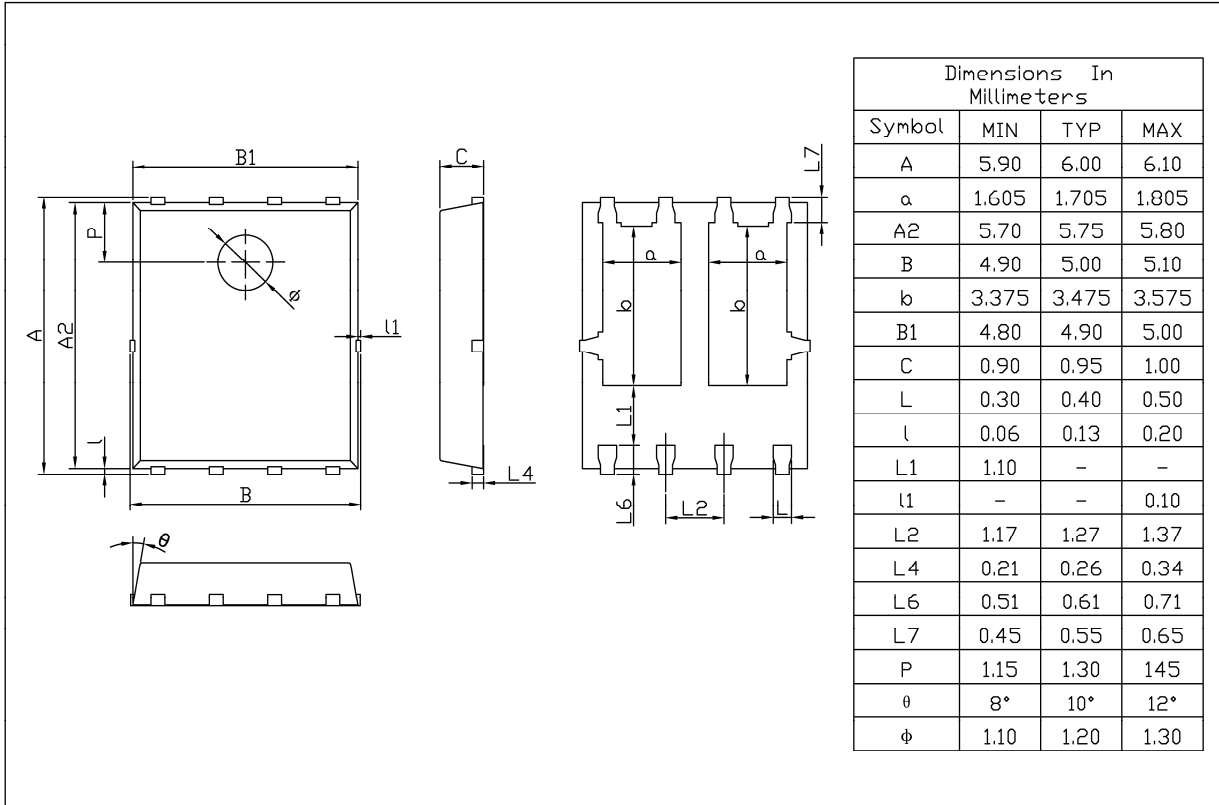


Figure 10: Normalized Maximum Transient Thermal Impedance

**外形尺寸图 / Package Dimensions**

PDFN5 X6A

Unit:mm

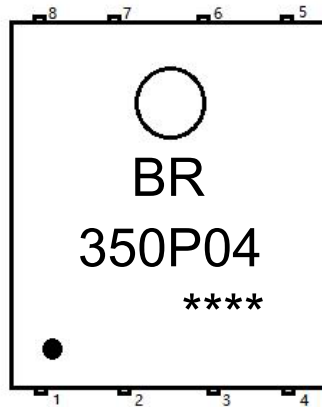


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## 印章说明 / Marking Instructions



说明：

BR： 为公司代码

350P04： 为产品型号

\*\*\*\*： 为生产批号代码，随生产批号变化

Note：

BR： Company Code

350P04： Product Type Code

\*\*\*\*: Lot No. Code, code change with Lot No

**回流焊温度曲线图(无铅) / Temperature Profile for IR Reflow Soldering(Pb-Free)**


说明：

- 1、预热温度 150~180°C，时间 60~90sec;
- 2、峰值温度 245±5°C，时间持续为 5±0.5sec;
- 3、焊接制程冷却速度为 2~10°C/sec.

Note:

- 1.Preheating:150~180°C, Time:60~90sec.
- 2.Peak Temp.:245±5°C, Duration:5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

**耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions**

温度：260±5°C

时间：10±1 sec.

Temp.:260±5°C

Time:10±1 sec

**包装规格 / Packaging SPEC.**

卷盘包装 / REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm <sup>3</sup> )		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
PDFN5×6A	5,000	2	10,000	6	60,000	13"×12	360×360×50	380×335×366

**使用说明 / Notices**